

The RFP2-30-50 is a Class A/AB amplifier, excellent as a driver stage in military, commercial, industrial, or scientific systems. Its high gain allows it to be driven to full power from signal generator levels. It utilizes a combination of three active device technologies for optimum performance and ruggedness, and is supplied with SMA input and output connectors.

Specifications $V_{sup} = +28VDC$, $I_{DQ} = 1.05A$, $P_{out} = 50W$, $T_{base} = 30^{\circ}C$, $Z_{load} = 50\Omega$					
Parameter	Min	Тур	Max	Units	
Freq. Range	2		30	MHz	
P _{1dB}	50	See Figure 4		W	
Input Power		-3	0	dBm	
Gain	47	50		dB	
Gain Flatness		+/-0.75	+/-1.5	dB	
Drain Current		4.05	4.40	А	
Efficiency	40	44		%	
IRL		-30	-20	dB	
f ₂		-31	-23	dBc	
f ₃		-13	-10	dBc	
$\frac{IMD_{3}}{50W \text{ PEP, } \Delta f=100 \text{ kHz}}$ See Fig. 2 for 10 kHz		-39	-32	dBc	
Dimensions	2.10 X 5.80 X 1.40 (53.34 X 147.32 X 35.56)		inch (mm)		

Maximum Ratings Operation beyond these ratings will void warranty.			
Parameter	Value		
V _{supply}	24-28VDC		
Bias Current	1.5A		
Drain Current	4.8A		
Load Mismatch*	3:1		
Baseplate Temperature	65°C		
Storage Temp.	-40°C to 85°C		

*All phase angles, 50W forward power, current limited to 4.8A for 5 seconds max.

Option Ordering Info		
Heatsink and fan	RFP2-30-50-HSF	
Enclosure with DC supply and fan (Mini-System)	RFPS2-30-50	

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RFP2-30-50



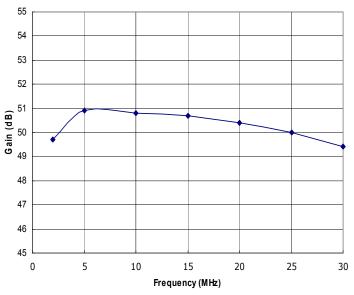


Figure 1: RFP2-30-50 Typical Gain @ Pout = 50W.

2-30MHz 50W Class A/AB High Performance Amplifier

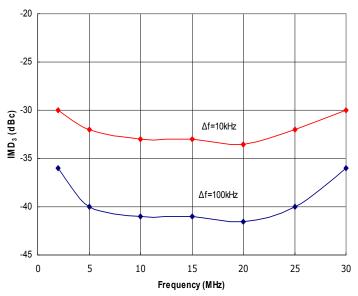


Figure 2: RFP2-30-50 Typical IMD₃ @ 50W PEP, Δf =10kHz and Δf =100kHz. For even greater linearity, see our RFP2-30-25 Class A amp.

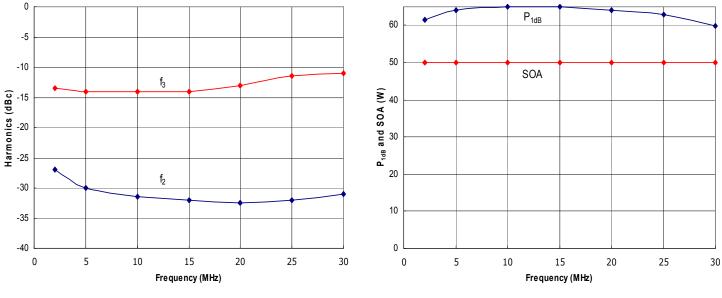


Figure 3: RFP2-30-50 Typical f_2 and $f_3 @ P_{out} = 50W$.

Figure 4: RFP2-30-50 Typical P_{1dB} and Safe Operating Area (SOA).

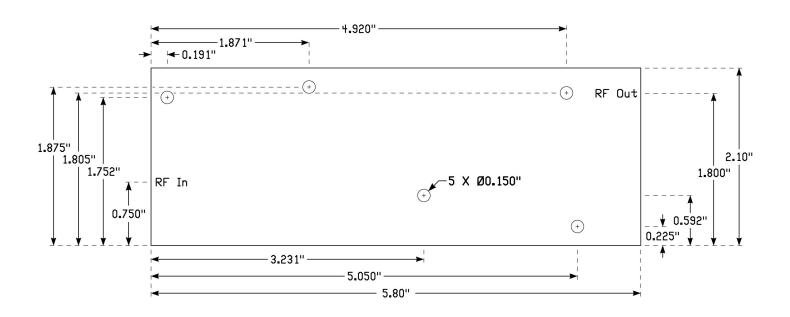






2-30MHz 50W Class A/AB High Performance Amplifier

Amplifier Mounting Hole and RF Locations



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RFP2-30-50

2-30MHz 50W Class A/AB High Performance Amplifier

Instructions for Amplifier Use

- 1) If not supplied with a heatsink, apply a layer of high quality thermal grease (Wakefield Type 120 or equivalent) to the underside of the amplifier baseplate. Thinner is better, but ensure that when mounted to your heatsink, contact across the *entire* baseplate is made. Gaps and air bubbles will significantly reduce cooling, leading to possible amplifier damage. Use five #6-32 screws to mount the amplifier to your heatsink.
- 2) Guarantee sufficient airflow through the heatsink fins to keep the maximum baseplate temperature at or less than that specified in the Maximum Ratings section. Contact RFMPT for details on how to qualify your heatsink's performance, if needed.
- 3) Connect a proper signal source to the RF IN connector, and desired load to the RF OUT connector. Torque connectors to industry standards for the type supplied with the amplifier.
- 4) Connect DC V_{supply} to the terminal provided. Solder a ground wire to the GND pad. Ensure that the connections are of proper polarity, and within the voltage range in the Maximum Ratings section.
- 5) Apply DC power and sufficient RF drive to achieve desired output level. Ensure that the Safe Operating Area (SOA) power level indicated in Figure 4 is not exceeded, or amplifier damage may occur, and will void the warranty.
- 6) To disconnect the amplifier, first remove the RF drive, then DC power, then the RF connections.

Contact the factory at <u>sales@rfmpt.com</u> with any questions, or for special options, testing requirements, and/or operating conditions not specified in this document.

Document Control

Revision	Date	Notes
Pre	4-26-2015	Preliminary release.
А	6-7-2015	Initial production release.
В	11-29-2017	Updated mechanical specifications, options, company name and logo.

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